## NSN 5961-01-131-2110

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-131-2110 **Inclosure Material:** Glass **Overall Length:** 4.200 millimeters **Terminal Length:** 25.000 millimeters **Overall Diameter:** 2.000 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.67 regulator voltage **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No